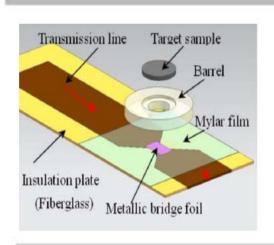
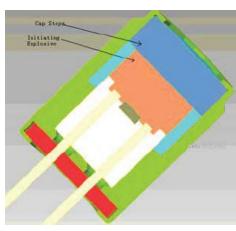
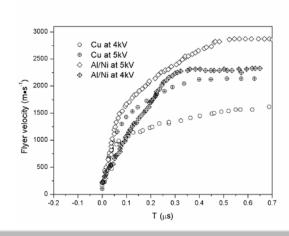
ICM Institute of Chemical Materials







Reactive Materials for electrical initiators

WANG YAO

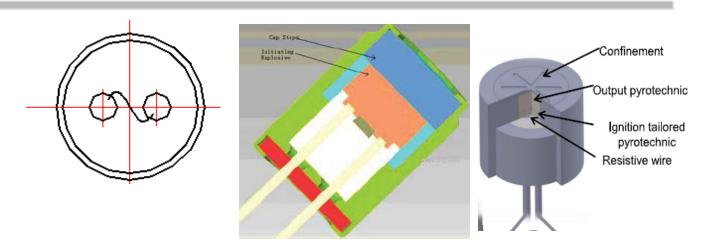
Email: wangyaocindi@caep.cn



Electrical initiators

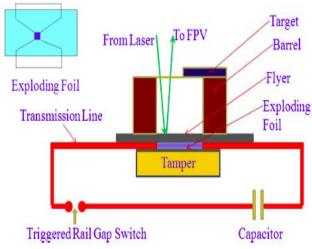
• ignition:

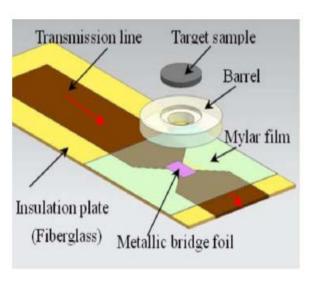
Resistance wire
Resistance bridge
SCB
Exploding wire



Explosion:Exploding foil







Reactive Materials

SAND98-1176C

To be presented at the 24th International Pyrotechnics Seminar,
Monterey, CA, July 1998

SAND

THEORETICAL ENERGY RELEASE OF THERMITES, INTERMETALLICS, AND COMBUSTIBLE METALS[†]

S. H. Fischer and M. C. Grubelich Sandia National Laboratories Albuquerque, NM 87185-1453

reactants		adiabatic reaction temperature (K)		state of products		gas production		heat of reaction	
constituents	ρ _{TMD} , g/cm ³	w/o phase changes	w/ phase changes	state of oxide	state of metal	moles gas per 100 g	g of gas per g	-Q, cal/g	-Q, cal/cm ³
2A1 + 3Cu ₂ O	5.280	4132	2843	liquid	l-g	0.1221	0.0776	575.5	3039
2Al +3NiO	5.214	3968	3187	liquid	l-g	0.0108	0.0063	822.3	4288
Be + CuO	5.119	3761	2820	s-l	liquid	0.0000	0.0000	1221	6249
2Al + 3CuO	5.109	5718	2843	liquid	I-g	0.5400	0.3431	974.1	4976
2Al + 3CoO	5.077	3392	3201	liquid	l-g	0.0430	0.0254	824.7	4187
3Ti + 2Fe ₂ O ₃	5.010	3358	2614	liquid	liquid	0.0000	0.0000	612.0	3066
Ti + Fe ₃ O ₄	4.974	3113	2334	liquid	liquid	0.0000	0.0000	563.0	2800
3Ti + 2Cr ₂ O ₃	4.959	1814	1814	solid	solid	0.0000	0.0000	296.2	1469

reactants		adiabatic reaction temperature (K)		state of intermetallic	gas pro	duction	heat of reaction		
constituents	ρ _{TMD} , g/cm ³	w/o phase changes	w/ phase changes	product	moles gas per 100 g	g of gas per g	-Q, cal/g	-Q, cal/cm ³	
Al + 2B	2.607	2251	>1252	l-g	0 - 2.1	0 - 1	742	1940	
4AI + 3C	2.574	1673	1673	solid	0.0	0.0	371	965	
2AI + Ca	2.051	2836	1738	liquid	0.0	0.0	558	1140	
4AI + Ca	2.248	1880	>972	s-l	0.0	0.0	348	782	
4Al + Ce	4.095	1173	1173	solid	0.0	0.0	126	458	
Al + Co	5.171	2195	>1912	s-l	0.0	0.0	307	1590	
4Al + Co	3.581	*	*	*	*	*	231	637	
5Al + 2Co	3.999	1755	>1452	s-l	0.0	0.0	277	1110	
3Al + Cr	3.568	793	793	solid	0.0	0.0	120	430	
Al + Cu	5.294	935	935	solid	0.0	0.0	108	573	
Al + Fe	4.844	1423	1423	solid	0.0	0.0	211	1020	
3Al + Fe	3.688	1407	1407	solid	0.0	0.0	278	1020	
4Al + La	3.946	1495	*	s-l	0.0	0.0	166	780	
Al + Li	1.476	1160	>972	s-l	0.0	0.0	345	509	
Al + Mn	4.676	803	803	solid	0.0	0.0	124	586	
Al + Ni	5.165	2362	>1910	s-l	0.0	0.0	330	1710	

• Al + CuO: $\Delta H = 974.1 \text{ cal/g}$;

• Al + Ni: $\Delta H = 330 \text{ cal/g}$;

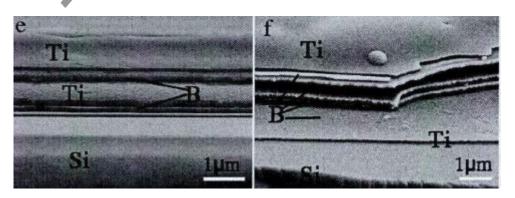
• B + Ti: $\Delta H = 1320 \text{ cal/g}$;



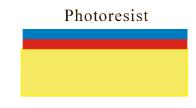
B/Ti reactive materials

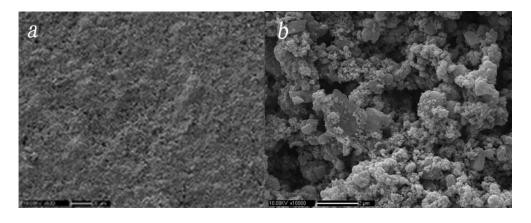
Thickness:3-4µm Bilayer:Ti(230nm) Bi(250nm)

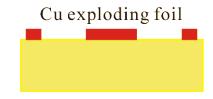
Cu film by magnetron sputtering

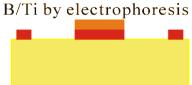




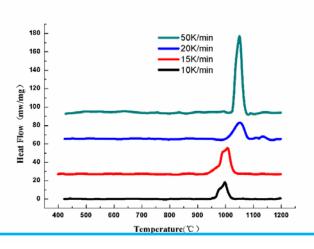




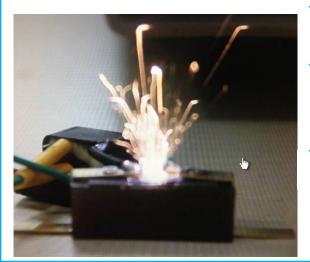




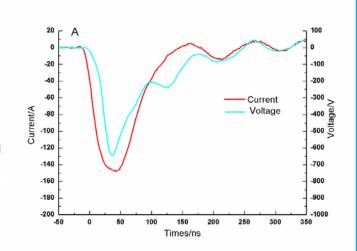
The exothermic reaction of B/Ti energetic materials:



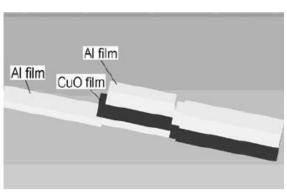
- ✓ Single exothermic reaction;
- ✓ Onset temperature is 976°C to 1023°C
 (< B 2076 °Cand Ti 1678 °C);
- ✓ Reaction heat was 1259J/g (<5517J/g).</p>

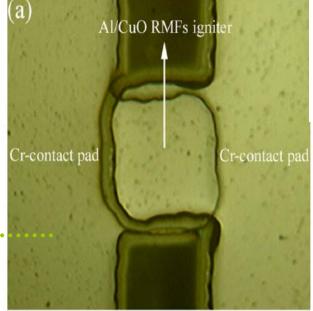


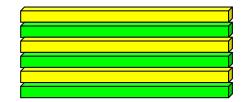
- ✓ Output energy:1.43mJ;
- Energy transformation efficiency: 71.5%;
- ✓ The height of flame can be reach to several millimeter.





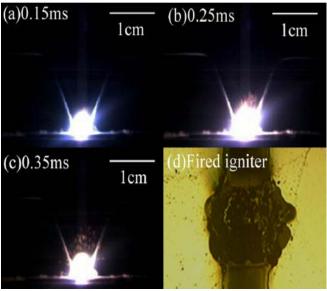








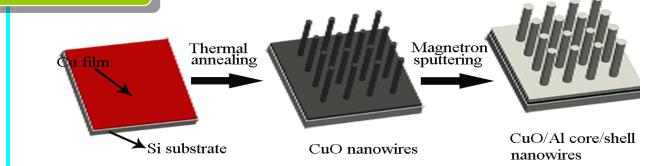
the igniter. The ignition delay time and total released energy of the igniter discharged in 40 V are 0.7 ms and 482.34 mJ, respectively. For one igniter, the energy released by chemical reactions is accounted for 21% of the total energy, which can be improved by adjusting the deposition conditions of Al/CuO RMFs and by tuning the Al deposition to reach a stoichiometric reaction. Furthermore, the explosion temperature could keep an approximately constant value of 3500 °C for 1.4 ms.



2

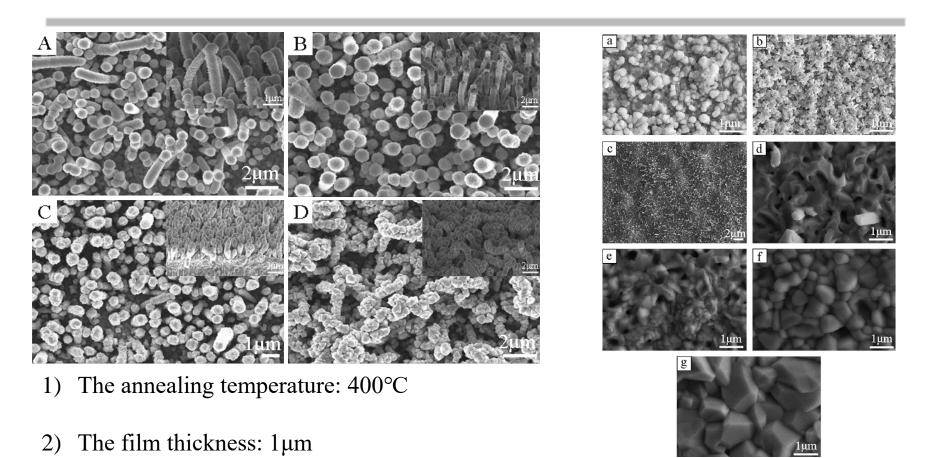
Al/CuO nanowires

- 1) Al/CuO nanowires grown from Cu thin film deposited onto silicon substrate.
- 2) The copper film is deposited by electro beam Evaporation.
- 3) The CuO nanowires is synthesized by annealing copper film.
- 4) The formation of Al₂O₃ would consume Al nanoparticles which reduce the heat reation.
- 5) The reaction between fuel and oxidizer should destroy Al₂O₃ which has high melting temperature



Processing	t _p /°C	$Q/(J \cdot g^{-1})$	Al/CuO摩尔比		
Ultrasonic wave	549. 5	473. 2	2: 3		
Sol-gel approaches	561. 2	574. 9	2: 3		
Core-shell	500	1085	-		

The core-shell structure



Magnetron sputtering

Ti~30nm

Electron beam evaporation

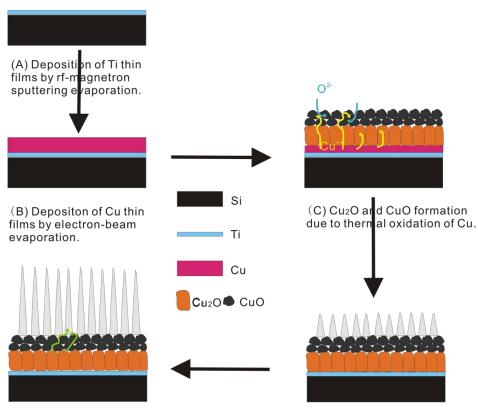
CuO nanowire

Thermal

oxidation

- 3) The electron-beam evaporation: 0.15A
- 4) The annealing time: 4h

The growth mechanism



(E) Completion of CuO nanowires

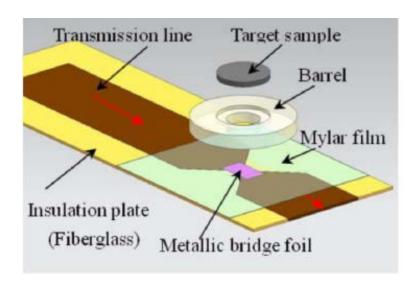
caused by residual stresses.

growth due to diffuse of Cu₂O atoms

(D) Start of CuO nanowires due to relief of compress stress.

The CuO growth mechanism:

- 1) Accumulation stress;
- 2) The appearance of apophysis;
- 3) The nucleation with apophysis;
- 4) The growth of nanowires



Traditonal metallic materials: Copper aluminum, gold and so on

Influence of AI/CuO reactive multilayer films additives on exploding foil initiator

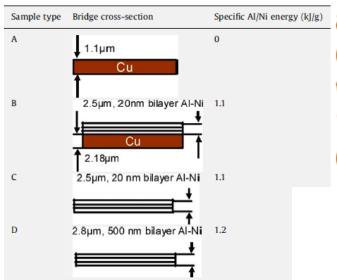
Xiang Zhou, Ruiqi Shen, Yinghua Ye, Peng Zhu, Yan Hu, and Lizhi Wu School of Chemical Engineering, Nanjing University of Science and Technology, Nanjing, China

(Received 19 June 2011; accepted 12 September 2011; published online 3 November 2011)

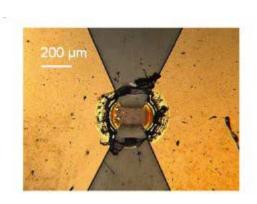
An investigation on the influence of Al/CuO reactive multilayer films (RMFs) additives on exploding foil initiator was performed in this paper. Cu film and Cu/Al/CuO RMFs were produced by using standard microsystem technology and RF magnetron sputtering technology, respectively. Scanning electron microscopy characterization revealed the distinct layer structure of the as-deposited Al/CuO RMFs. Differential scanning calorimetry was employed to ascertain the amount of heat released in the thermite reaction between Al films and CuO films, which was found to be 2024 J/g. Electrical explosion tests showed that 600 V was the most matching voltage for our set of apparatus. The explosion process of two types of films was observed by high speed camera and revealed that compared with Cu film, an extra distinct combustion phenomenon was detected with large numbers of product particles fiercely ejected to a distance of about six millimeters for Cu/Al/CuO RMFs. By using the atomic emission spectroscopy double line technique, the reaction temperature was determined to be about 6000-7000 K and 8000-9000 K for Cu film and Cu/Al/ CuO RMFs, respectively. The piezoelectricity of polyvinylidene fluoride film was employed to measure the average velocity of the slapper accelerated by the explosion of the films. The average velocities of the slappers were calculated to be 381 m/s and 326 m/s for Cu film and Cu/Al/CuO RMFs, respectively, and some probable reasons were discussed with a few suggestions put forward for further work. © 2011 American Institute of Physics. [doi:10.1063/1.3658617]

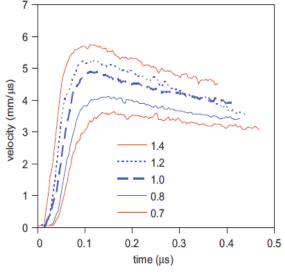
Al/CuO multilayer: did not improve flyer velocity

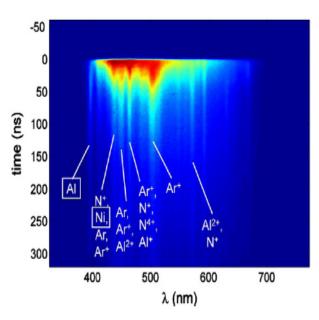
Disadvantage: low power transduction efficiency



application of a large electrical current. We observed flyer plate velocities in the 2–6 km/s range, corresponding to 4–36 kJ/g in terms of specific kinetic energy. Several samples containing Ni/Al films with different bilayer thicknesses were tested, and many produced additional kinetic energy in the 1.1–2.3 kJ/g range, as would be expected from the Ni–Al intermetallic reaction. These results provide evidence that nanoscale Ni/Al layers reacted in the timescale necessary to contribute to device output.







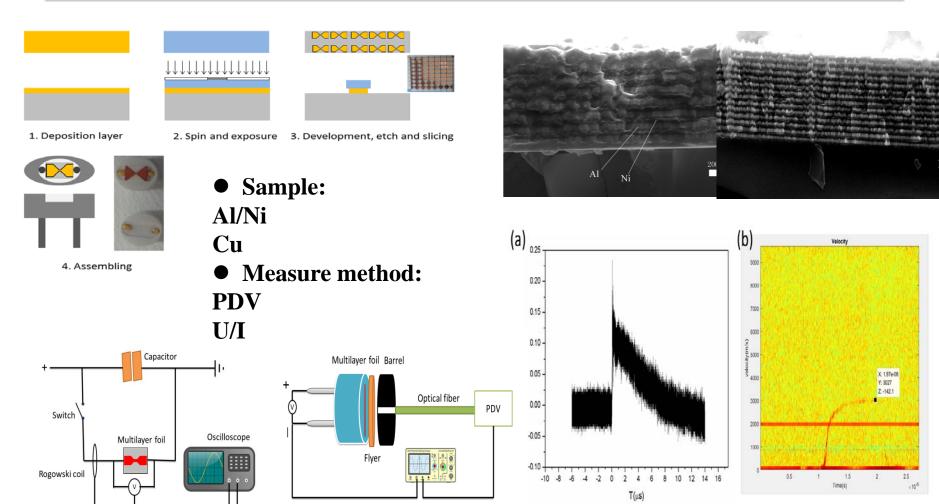
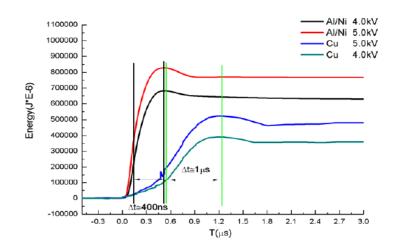
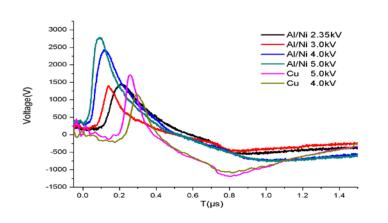


Fig. 5 (a): Current histories for Al/Ni and Cu film, (b): Voltage histories for Al/Ni and Cu film Table.1 Results of exploding foil

N o.	Mate rial	Resista nce of foil mΩ	Inpu t volta ge V	Peak volta ge V	Tim e of peak volta ge ns	peak curr ent A	Tim e of peak curr ent ns	Pea k ener gy mJ	Maxim um energy mJ	Inpu t ener gy mJ	Energ y efficie ncy	∆t ns
1	Al/Ni	110	2350	1456	204	120 3	201	110	340	610	18%	33 7
2	Al/Ni	104	3000	1500	140	139 5	239	66	300	990	6.7%	34 6
3	Al/Ni	105	4000	2416	120	149 8	261	170	650	176 0	9.7%	36 6
4	Al/Ni	103	5000	2768	103	176 0	273	240	780	275 0	8.7%	37 6
5	Cu	26.2	5000	1717	260	301 4	240	160	690	275 0	5.8%	12 45
6	Cu	26.5	4000	1157	275	248 9	235	45	470	176 0	2.6%	11 80
∆t:	△t: The time of maximum energy minus time of peak voltage											

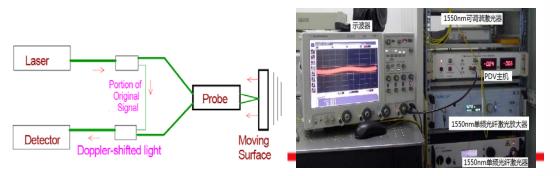


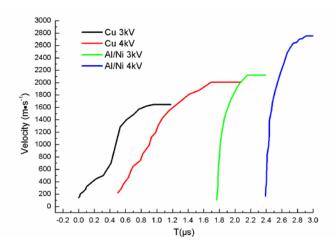


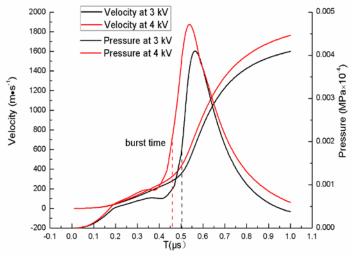
D. Photonic Doppler velocimetry (PDV)

In a separate set of tests with identical samples, we used PDV to measure the resulting velocities of the flyer material when connected to the same high voltage firing circuit used in the streak spectroscopy measurements. This technique quantified the Doppler shift in frequency $\Delta f(t)$ of light reflected off a moving target—in this case the flyer—relative to the light emitted from the end of a fiber optic probe. The measured difference in frequency $\Delta f(t)$ is related to the flyer velocity $u_f(t)$ according to

$$\Delta f(t) = 2\frac{u_f(t)}{\lambda_0},\tag{6}$$







Thank you for your attention

